

1. General description

Dual common cathode power Schottky diode in TO263 (D2PAK) package.



2. Features and benefits

- High junction temperature up to 150 °C
- High efficiency
- Low forward voltage drop, negligible switching losses

3. Applications

- DC to DC converters
- Freewheeling diode
- OR-ing diode
- Switched mode power supply rectifier

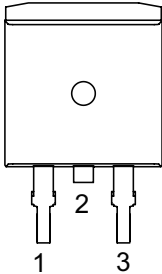
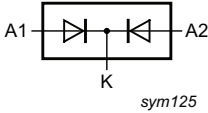
4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Notes	Values			Unit
Absolute maximum rating							
V _{RRM}	repetitive peak reverse voltage			100			V
I _{F(AV)}	average forward current	δ = 0.5 ; square-wave pulse; T _{mb} ≤ 130 °C; per diode; Fig. 1 ; Fig. 2 ; Fig. 3		10			A
I _{O(AV)}	average output current	δ = 0.5 ; square-wave pulse; T _{mb} ≤ 131 °C; both diodes conducting		20			A
Symbol	Parameter	Conditions	Notes	Min	Typ	Max	Unit
Static characteristics							
V _F	forward voltage	I _F = 10 A; T _j = 25 °C; per diode; Fig. 6		-	0.68	0.75	V
I _R	reverse current	V _R = 100 V; T _j = 25 °C; per diode; Fig. 7		-	7	50	μA

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	A	anode 1		 sym125
2	K	cathode		
3	A	anode 2		
mb	mb	mounting base; connected to cathode		

6. Ordering information

Table 3. Ordering information

Type number	Package name	Orderable part number	Packing method	Small packing quantity	Package version	Package issue date
WN3S20H100CB	TO263	WN3S20H100CBJ	Reel	800	TO263d	17-Mar-2023

7. Marking

Table 4. Marking codes

Type number	Marking codes
WN3S20H100CB	WN3S20H 100CB

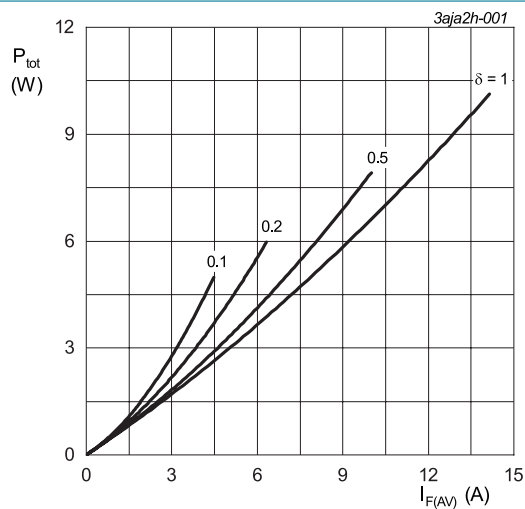
8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Notes	Values	Unit
V_{RRM}	repetitive peak reverse voltage			100	V
V_{RWM}	crest working reverse voltage			100	V
V_R	reverse voltage	DC		100	V
$I_{F(AV)}$	average forward current	$\delta = 0.5$; square-wave pulse; $T_{mb} \leq 130\text{ }^{\circ}\text{C}$; per diode; Fig. 1 ; Fig. 2 ; Fig. 3		10	A
$I_{O(AV)}$	average output current	$\delta = 0.5$; square-wave pulse; $T_{mb} \leq 131\text{ }^{\circ}\text{C}$; both diodes conducting		20	A
I_{FSM}	non-repetitive peak forward current	$t_p = 10\text{ ms}$; $T_{j(\text{init})} = 25\text{ }^{\circ}\text{C}$; sine-wave pulse; per diode; Fig. 4		180	A
		$t_p = 8.3\text{ ms}$; $T_{j(\text{init})} = 25\text{ }^{\circ}\text{C}$; sine-wave pulse; per diode		198	A
T_{stg}	storage temperature			-40 to 150	$^{\circ}\text{C}$
T_j	junction temperature		[1]	-40 to 150	$^{\circ}\text{C}$

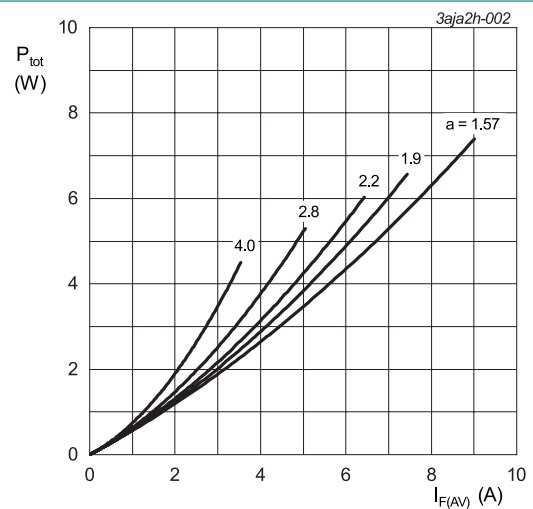
[1] The heat generated must be less than the thermal conductivity from Junction to Ambient: $dP_{tot}/dT_j < 1/R_{th(j-a)}$



$$I_{F(AV)} = I_{F(RMS)} \times \sqrt{\delta}$$

$$V_o = 0.531\text{ V}; R_s = 0.0131\text{ }\Omega$$

Fig. 1. Forward power dissipation as a function of average forward current; square waveform; maximum values; per diode



$$a = \text{form factor} = I_{F(RMS)} / I_{F(AV)}$$

$$V_o = 0.531\text{ V}; R_s = 0.0131\text{ }\Omega$$

Fig. 2. Forward power dissipation as a function of average forward current; sinusoidal waveform; maximum values; per diode

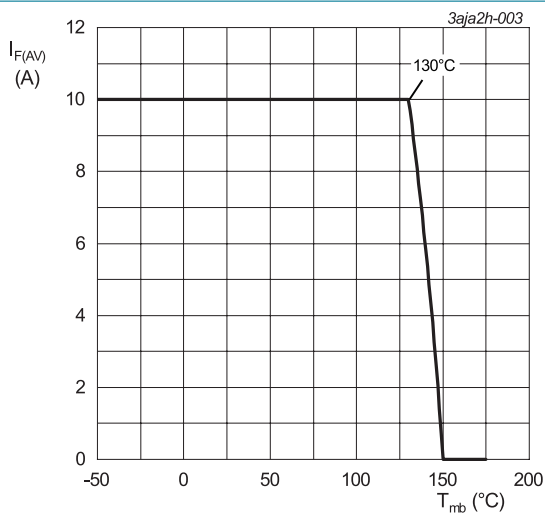


Fig. 3. Average forward current as a function of mounting base temperature; maximum values; per diode

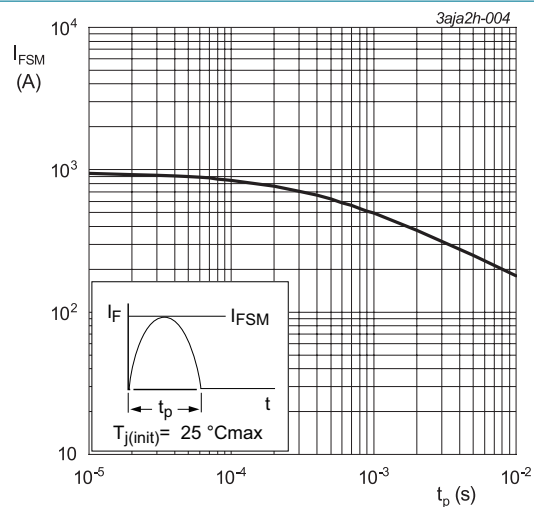


Fig. 4. Non-repetitive peak forward current as a function of pulse width; sinusoidal waveform; maximum values; per diode

9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Notes	Min	Typ	Max	Unit
$R_{th(j-mb)}$	thermal resistance from junction to mounting base	per diode; Fig. 5		-	-	2.5	K/W
		both diodes conducting		-	-	1.2	K/W
$R_{th(j-a)}$	thermal resistance from junction to ambient free air	in free air		-	60	-	K/W

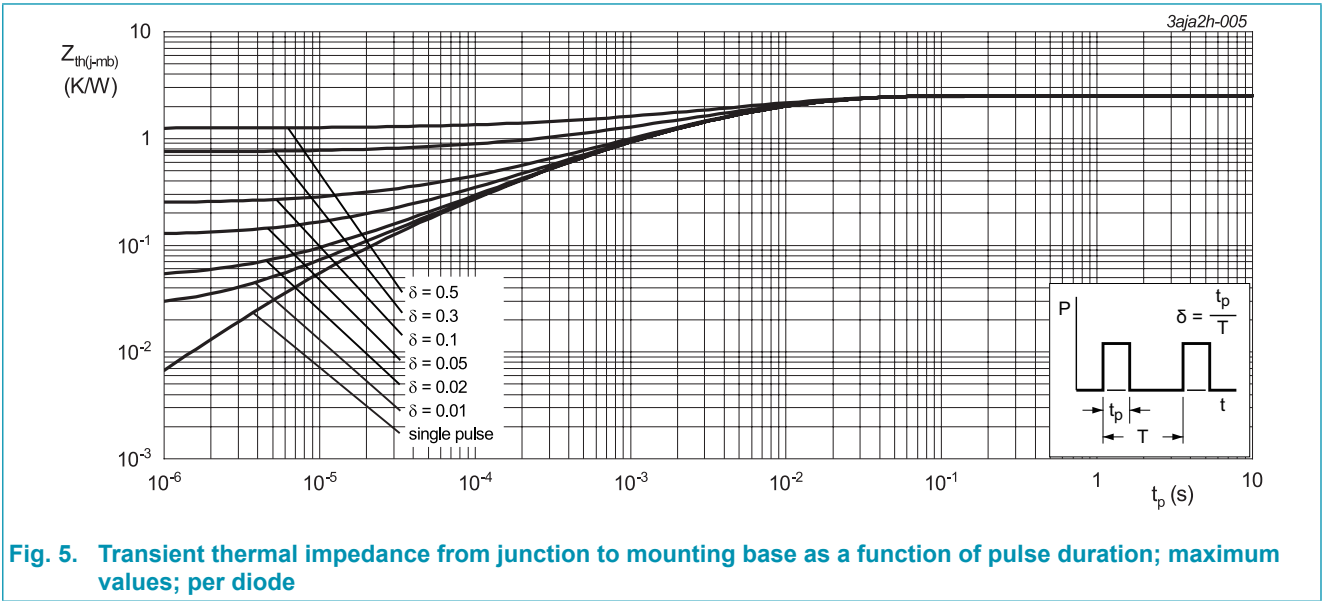
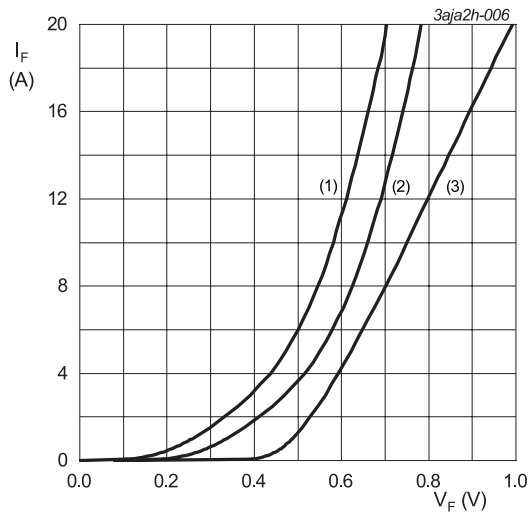


Fig. 5. Transient thermal impedance from junction to mounting base as a function of pulse duration; maximum values; per diode

10. Characteristics

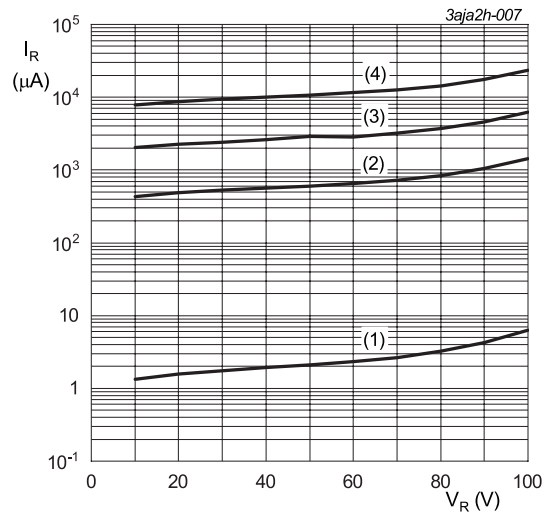
Table 7. Characteristics

Symbol	Parameter	Conditions	Notes	Min	Typ	Max	Unit
Static characteristics							
V _F	forward voltage	I _F = 10 A; T _j = 25 °C; per diode; Fig. 6		-	0.68	0.75	V
		I _F = 10 A; T _j = 125 °C; per diode; Fig. 6		-	0.63	-	V
		I _F = 10 A; T _j = 150 °C; per diode; Fig. 6		-	0.58	-	V
		I _F = 5 A; T _j = 25 °C; per diode; Fig. 6		-	0.54	-	V
		I _F = 5 A; T _j = 125 °C; per diode; Fig. 6		-	0.51	-	V
I _R	reverse current	V _R = 100 V; T _j = 25 °C; per diode; Fig. 7		-	7	50	μA
		V _R = 100 V; T _j = 125 °C; per diode; Fig. 7		-	7	-	mA



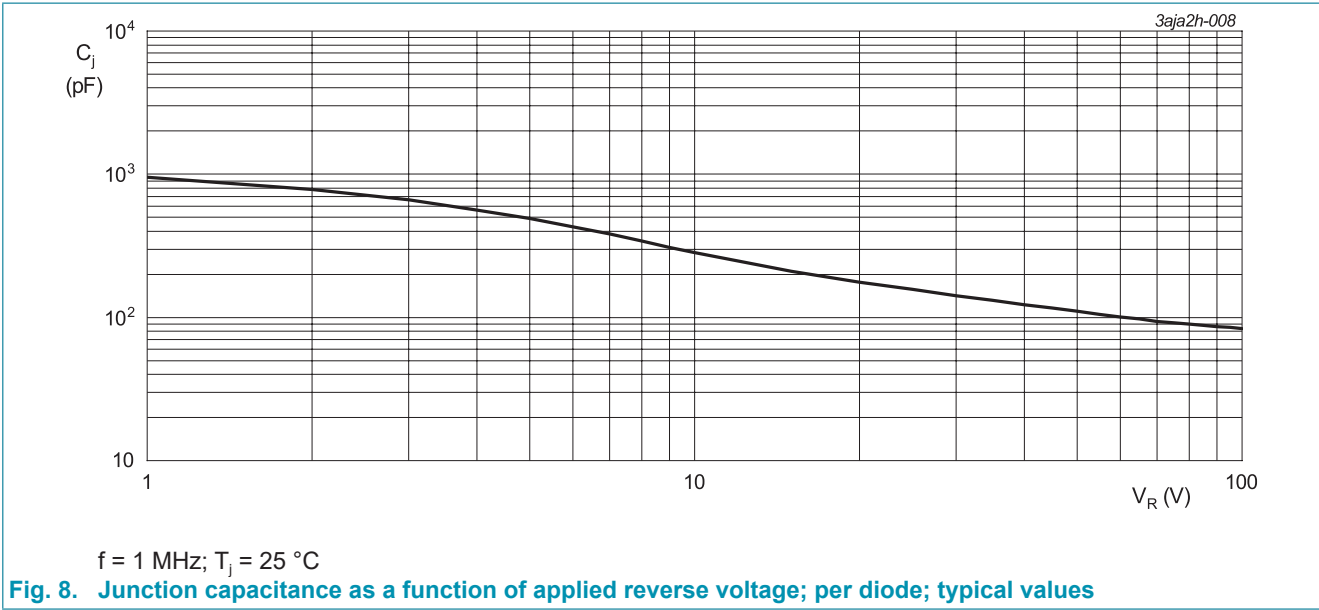
V₀ = 0.531 V; R_s = 0.0131 Ω
(1) T_j = 150 °C; typical values
(2) T_j = 150 °C; maximum values
(3) T_j = 25 °C; maximum values

Fig. 6. Forward current as a function of forward voltage; per diode



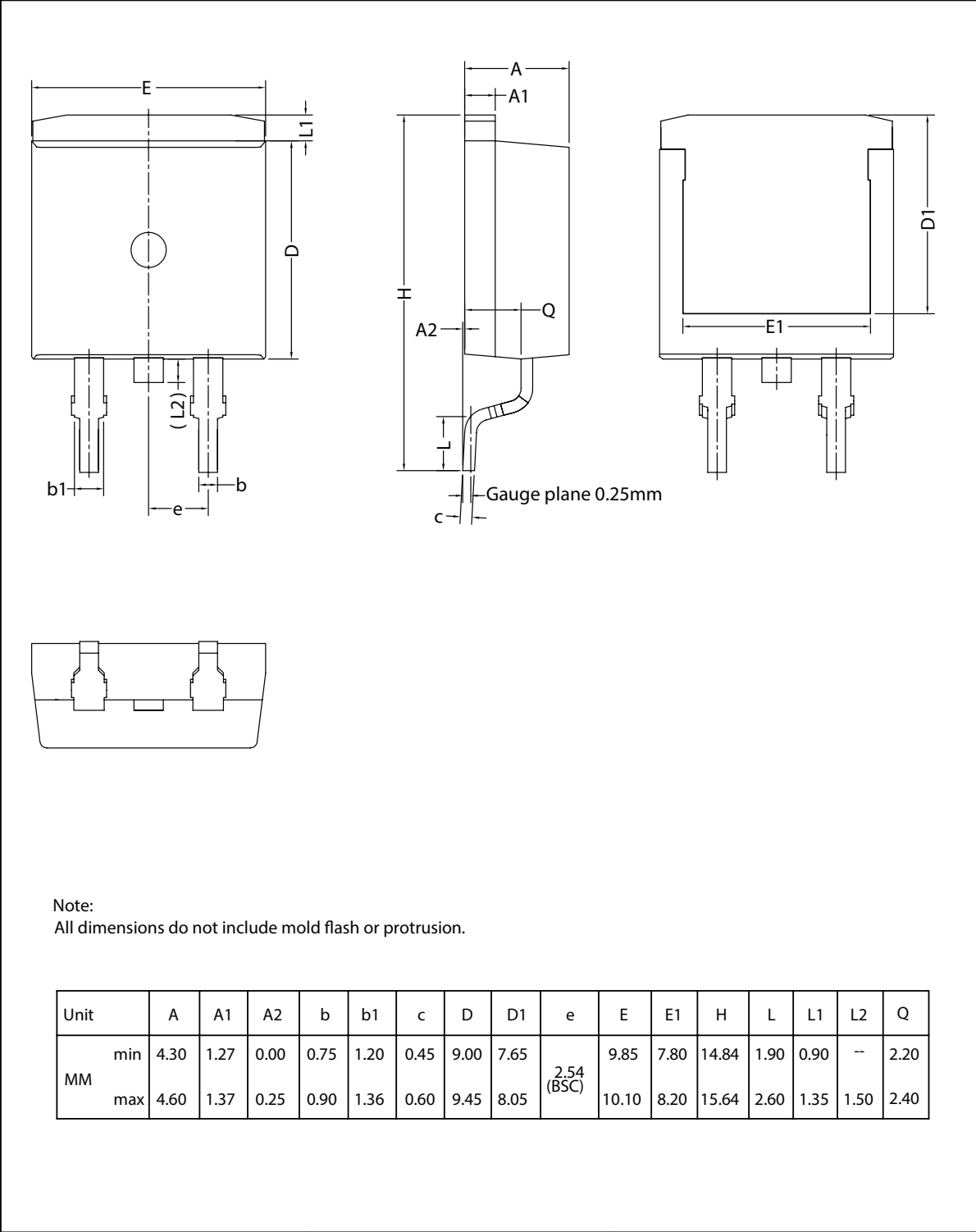
(1) T_j = 25 °C; typical values
(2) T_j = 100 °C; typical values
(3) T_j = 125 °C; typical values
(4) T_j = 150 °C; typical values

Fig. 7. Reverse leakage current as a function of reverse voltage; per diode; typical values



11. Package outline

Plastic single-ended surface-mounted package (D2PAK); TO263



12. Legal information

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Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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- [2] The term 'short data sheet' is explained in section "Definitions".
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13. Contents

1. General description..... 1

2. Features and benefits 1

3. Applications 1

4. Quick reference data..... 1

5. Pinning information..... 2

6. Ordering information..... 2

7. Marking..... 2

8. Limiting values 3

9. Thermal characteristics 5

10. Characteristics..... 6

11. Package outline 8

12. Legal information 9

13. Contents 11

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